

PDTA114ET-Q

50 V, 100 mA PNP resistor-equipped transistor; R1 = 10 k Ω , R2 = 10 k Ω

7 February 2023

Product data sheet

1. General description

PNP Resistor-Equipped Transistor (RET) in a small SOT23 (TO-236AB) Surface-Mounted Device (SMD) plastic package.

NPN complement: PDTC114ET-Q

2. Features and benefits

- 100 mA output current capability
- · Built-in bias resistors
- Simplifies circuit design
- Reduces component count
- Reduces pick and place costs
- Qualified according to AEC-Q101 and recommended for use in automotive applications

3. Applications

- Digital application in automotive and industrial segments
- · Cost-saving alternative for BC847-Q series in digital applications
- Controlling IC inputs
- · Switching loads

4. Quick reference data

Table 1. Quick reference data

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
V _{CEO}	collector-emitter voltage	open base		-	-	-50	V
Io	output current			-	-	-100	mA
R1	bias resistor 1 (input)		[1]	7	10	13	kΩ
R2/R1	bias resistor ratio		[1]	0.8	1	1.2	

[1] See "Section 11: Test information" for resistor calculation and test conditions.



50 V, 100 mA PNP resistor-equipped transistor; R1 = 10 k Ω , R2 = 10 k Ω

5. Pinning information

Table 2. Pinning information

Pin	Symbol	Description	Simplified outline	Graphic symbol
1	I	input (base)]3	☐ d c
2	GND	ground (emitter)		B R1
3	0	output (collector)	SOT23	R2 E sym003

6. Ordering information

Table 3. Ordering information

Type number	Package					
	Name	Description	Version			
PDTA114ET-Q	SOT23	plastic, surface-mounted package; 3 terminals; 1.9 mm pitch; 2.9 mm x 1.3 mm x 1 mm body	SOT23			

7. Marking

Table 4. Marking codes

Type number	Marking code[1]
PDTA114ET-Q	803

^{[1] % =} placeholder for manufacturing site code

8. Limiting values

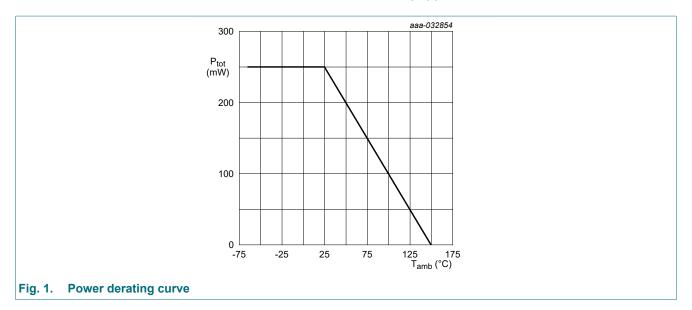
Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions		Min	Max	Unit
V_{CBO}	collector-base voltage	open emitter		-	-50	V
V_{CEO}	collector-emitter voltage	open base		-	-50	V
V_{EBO}	emitter-base voltage	open collector		-	-10	V
VI	input voltage			-40	10	V
I _O	output current			-	-100	mA
P _{tot}	total power dissipation	T _{amb} ≤ 25 °C	[1]	-	250	mW
Tj	junction temperature			-	150	°C
T _{amb}	ambient temperature			-65	150	°C
T _{stg}	storage temperature			-65	150	°C

^[1] Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided, 35 µm copper, tin-plated and standard footprint.

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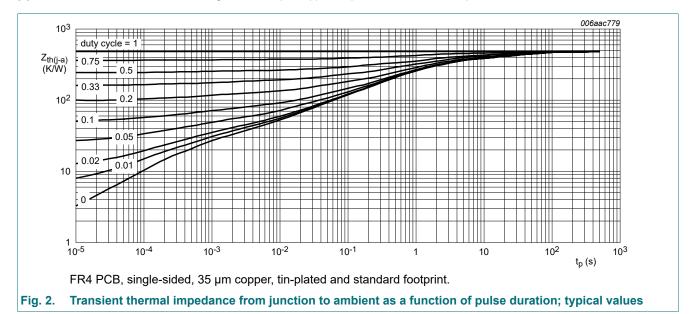


9. Thermal characteristics

Table 6. Thermal characteristics

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
$R_{th(j-a)}$	thermal resistance from junction to ambient	in free air	[1]	-	-	500	K/W

[1] Device mounted on an FR4 PCB, single-sided, 35 µm copper, tin-plated and standard footprint.



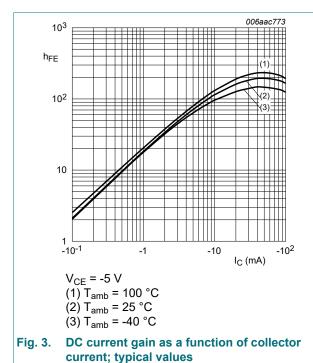
50 V, 100 mA PNP resistor-equipped transistor; R1 = 10 k Ω , R2 = 10 k Ω

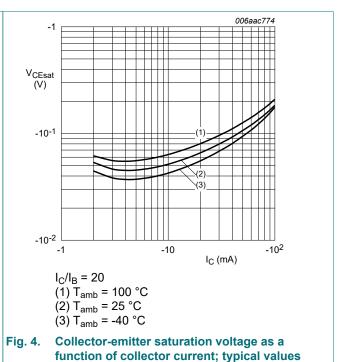
10. Characteristics

Table 7. Characteristics

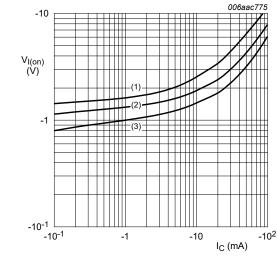
Symbol	Parameter	Conditions		Min	Тур	Max	Unit
V _{(BR)CBO}	collector-base breakdown voltage	$I_C = -100 \ \mu A; I_E = 0 \ A; T_{amb} = 25 \ ^{\circ}C$		-50	-	-	V
$V_{(BR)CEO}$	collector-emitter breakdown voltage	$I_C = -2 \text{ mA}; I_B = 0 \text{ A}; T_{amb} = 25 \text{ °C}$		-50	-	-	V
I _{CBO}	collector-base cut-off current	V _{CB} = -50 V; I _E = 0 A; T _{amb} = 25 °C		-	-	-100	nA
I _{CEO}	collector-emitter cut-off	V _{CE} = -30 V; I _B = 0 A; T _{amb} = 25 °C		-	-	-1	μΑ
	current	V _{CE} = -30 V; I _B = 0 A; T _j = 150 °C		-	-	-5	μΑ
I _{EBO}	emitter-base cut-off current	V _{EB} = -5 V; I _C = 0 A; T _{amb} = 25 °C		-	-	-400	μΑ
h _{FE}	DC current gain	V _{CE} = -5 V; I _C = -5 mA; T _{amb} = 25 °C		30	-	-	
V _{CEsat}	collector-emitter saturation voltage	I_C = -10 mA; I_B = -0.5 mA; T_{amb} = 25 °C		-	-	-150	mV
$V_{I(off)}$	off-state input voltage	V_{CE} = -5 V; I_{C} = -100 μ A; T_{amb} = 25 °C		-	-1.1	-0.8	V
V _{I(on)}	on-state input voltage	V_{CE} = -0.3 V; I_{C} = -10 mA; T_{amb} = 25 °C		-2.5	-1.8	-	V
R1	bias resistor 1 (input)		[1]	7	10	13	kΩ
R2/R1	bias resistor ratio		[1]	8.0	1	1.2	
C _c	collector capacitance	V _{CB} = -10 V; I _E = 0 A; i _e = 0 A; f = 1 MHz; T _{amb} = 25 °C		-	-	3	pF
f _T	transition frequency	V_{CE} = -5 V; I_{C} = -10 mA; f = 100 MHz; T_{amb} = 25 °C	[2]	-	180	-	MHz

- [1] See "Section 11: Test information" for resistor calculation and test conditions.
- [2] Characteristics of built-in transistor.





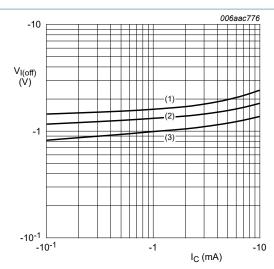
50 V, 100 mA PNP resistor-equipped transistor; R1 = 10 k Ω , R2 = 10 k Ω



$$V_{CE} = -0.3 \text{ V}$$

$$(1) T_{amb} = -40 °C$$

Fig. 5. On-state input voltage as a function of collector | Fig. 6. current; typical values



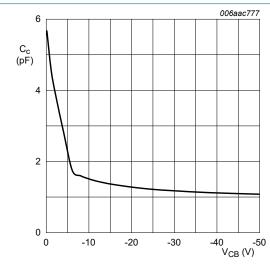
$$V_{CE} = -5 V$$

$$(1) T_{amb} = -40 °C$$

(2)
$$T_{amb} = 25 \, ^{\circ}C$$

V_{CE} = -5 V (1) T_{amb} = -40 °C (2) T_{amb} = 25 °C (3) T_{amb} = 100 °C

Off-state input voltage as a function of collector current; typical values



 $f = 1 MHz; T_{amb} = 25 °C$



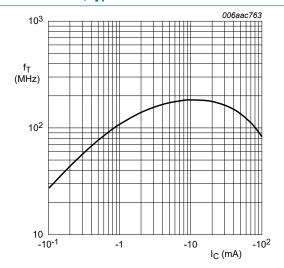


Fig. 8. Transition frequency as a function of collector current; typical values of built-in transistor

50 V, 100 mA PNP resistor-equipped transistor; R1 = 10 k Ω , R2 = 10 k Ω

11. Test information

Quality information

This product has been qualified in accordance with the Automotive Electronics Council (AEC) standard Q101 - Stress test qualification for discrete semiconductors, and is suitable for use in automotive applications.

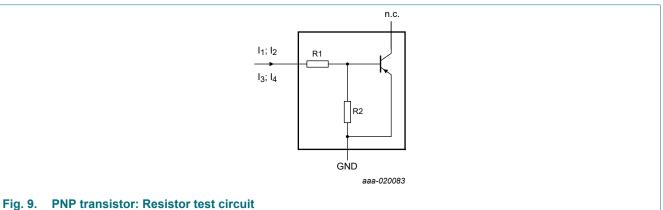
Resistor calculation

Calculation of bias resistor 1 (R1)

$$R_{I} = \frac{V(I_{2}) - V(I_{1})}{I_{2} - I_{1}}$$

· Calculation of bias resistor ratio (R2/R1)

$$\frac{R2}{R1} = \frac{V(I4) - V(I3)}{R1 \cdot (I4 - I3)} - 1$$



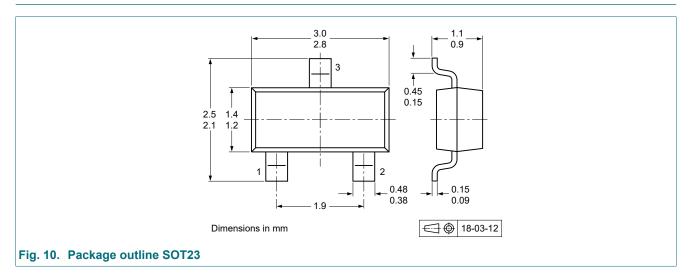
Resistor test conditions

Table 8. Resistor test conditions

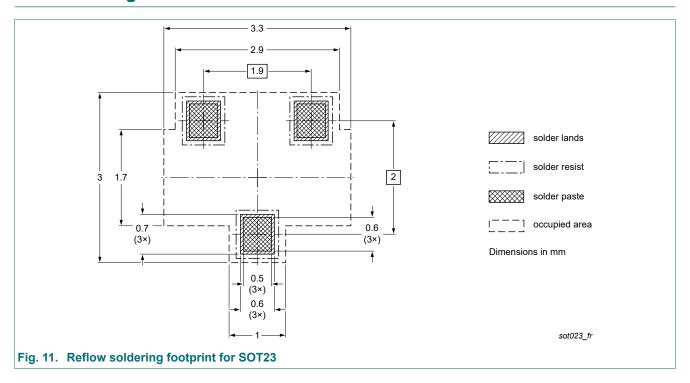
Type number	R1 (kΩ)	R2 (kΩ)	Test conditions			
			I ₁	l ₂	l ₃	14
PDTA114ET-Q	10	10	-350 μΑ	-450 μΑ	350 μΑ	450 μΑ

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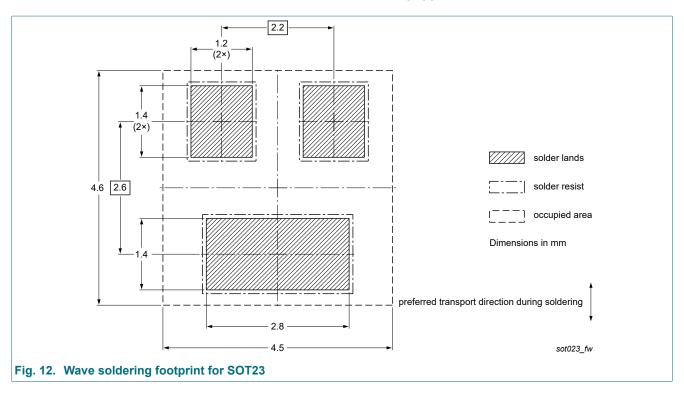
12. Package outline



13. Soldering



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50 V, 100 mA PNP resistor-equipped transistor; R1 = 10 k Ω , R2 = 10 k Ω

14. Revision history

Table 9. Revision history

Data sheet ID	Release date	Data sheet status	Change notice	Supersedes			
PDTA114ET-Q v.2	20230207	Product data sheet	-	-			
Modifications:	 Limiting value 	es: Values for Input voltage cor	rected				
PDTA114ET-Q v.1	20220225	Product data sheet	-	-			

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15. Legal information

Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

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- [2] The term 'short data sheet' is explained in section "Definitions".
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